



#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on) max</sub>	<b>l</b> <sub>D</sub> Τ <sub>C</sub> = +25°C
-40V	$11m\Omega$ @ $V_{GS} = -10V$	-35A
- <del>4</del> 0V	15mΩ @ V <sub>GS</sub> = -4.5V	-30A

## **Description**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- DC-DC Converters
- Power management functions
- Backlighting

## **Features and Benefits**

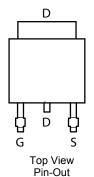
- 100% Unclamped Inductive Switch (UIS) test in production
- Low on-resistance
- Fast switching speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

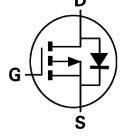
#### **Mechanical Data**

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208<sup>3</sup>
- Weight: 0.33 grams (approximate)









**Equivalent Circuit** 

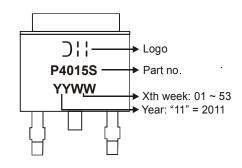
## Ordering Information (Note 4)

Part Number Compli		Case	Packaging	
DMP4015SK3-13	Standard	TO252	2,500/Tape & Reel	
DMP4015SK3Q-13	Automotive	TO252	2,500/Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

## **Marking Information**





## Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	$V_{DSS}$	-40	V		
Gate-Source Voltage	$V_{GSS}$	±25	V		
Continuous Drain Current (Note 5) V <sub>GS</sub> = -10V	I <sub>D</sub>	-35 -27	Α		
Continuous Drain Current (Note EVV - 40V	Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$		I <sub>D</sub>	-14 -11	Α
Continuous Drain Current (Note 5) V <sub>GS</sub> = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-22 -18	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	-100	Α		
Maximum Body Diode Forward Current (Note 5)	Is	-5.5	Α		
Avalanche Current (Note 6)	I <sub>AS</sub>	-57	Α		
Avalanche Energy (Note 6)	Eas	162	mJ		

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	r -	3.5	- W
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	P <sub>D</sub>	2.2	
Thermal Desigtance, Junction to Ambient (Note 5)	Steady state	_	36	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	15	
Thermal Resistance, Junction to Case (Note 5)  Steady state		$R_{ heta JC}$	4.5	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	_	_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.5	-2.0	-2.5	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain Source On Decistance		_	7	11	0	$V_{GS} = -10V, I_D = -9.8A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	9	15	mΩ	$V_{GS} = -4.5V, I_D = -9.8A$	
Forward Transfer Admittance	Y <sub>fs</sub>	_	26	_	S	$V_{DS} = -20V, I_{D} = -9.8A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.0	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	4234	_		V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss	_	1036	_	pF		
Reverse Transfer Capacitance	Crss	_	526	_		I - I.OIVIHZ	
Gate Resistance	R <sub>G</sub>	_	7.77	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	_	47.5	_			
Gate-Source Charge	Qgs	_	14.2	_	nC	$V_{DS} = -20V, V_{GS} = -5V$ $I_D = -9.8A$	
Gate-Drain Charge	$Q_{gd}$	_	13.5	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	13.2	_			
Turn-On Rise Time	t <sub>r</sub>	_	10.0	_		$V_{GS} = -10V, V_{DD} = -20V,$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	302.7	_	ns	$R_G = 6\Omega$ , $I_D = -1A$	
Turn-Off Fall Time	t <sub>f</sub>	_	137.9	_			

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 6. UIS in production with L = 0.1 mH,  $T_J = +25^{\circ}\text{C}$ .
- 7 .Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.



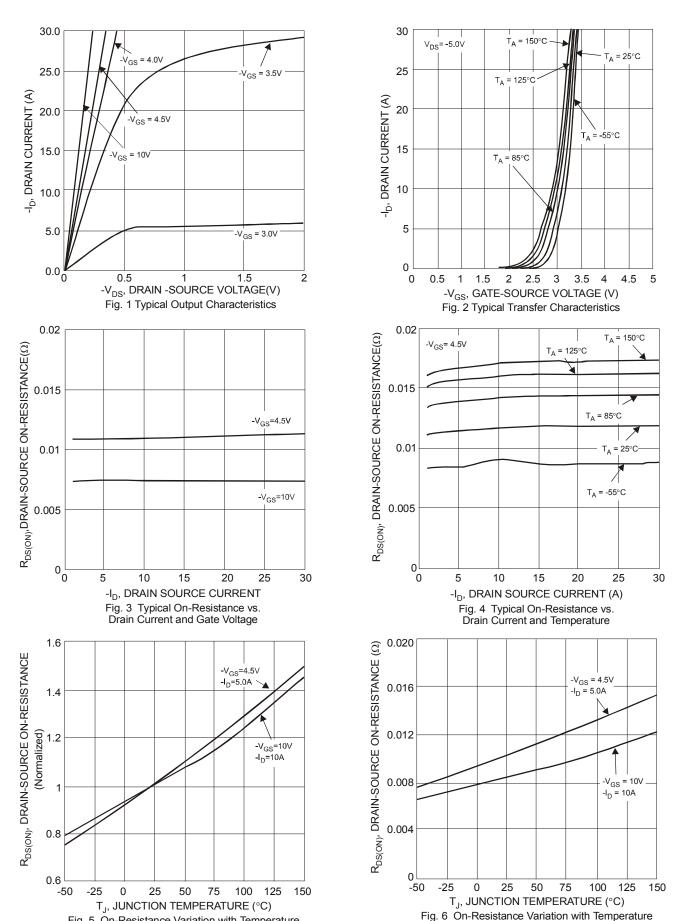


Fig. 5 On-Resistance Variation with Temperature



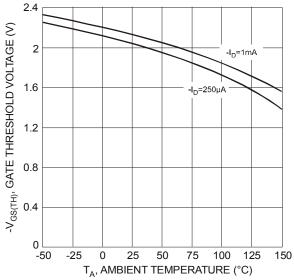
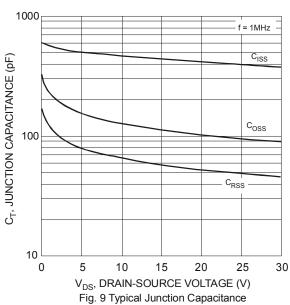
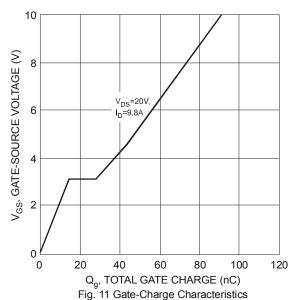
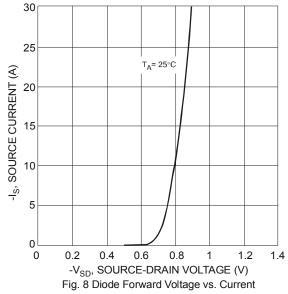


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







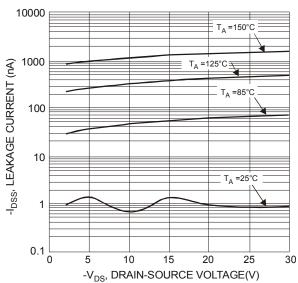


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

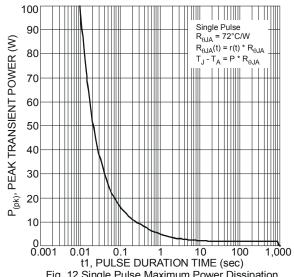
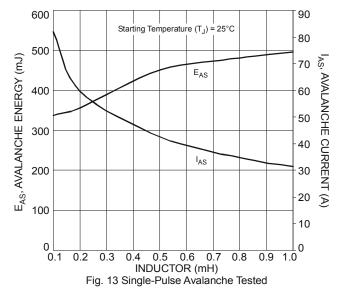
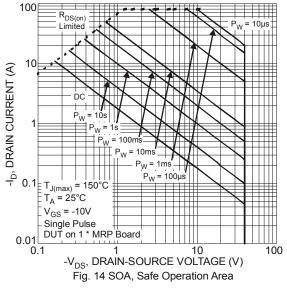
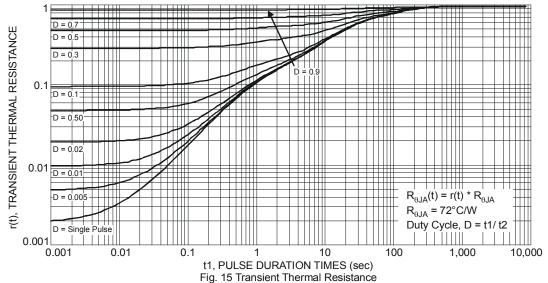


Fig. 12 Single Pulse Maximum Power Dissipation



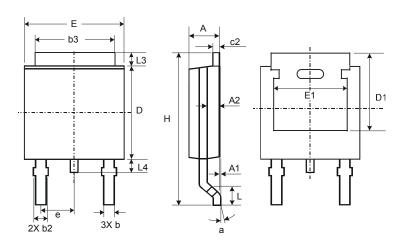






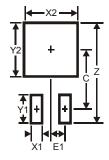


# **Package Outline Dimensions**



TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	1 5.21 –		_		
е	_	_	2.286		
Е	6.45	6.70	6.58		
E1	4.32	_	_		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3



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Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

## Customer Service :

Email service@ameya360.com

# Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com